Renesas Electronics America Inc - M30845FJGP#U5 Datasheet

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Not For New Designs
Core Processor	M32C/80
Core Size	16/32-Bit
Speed	32MHz
Connectivity	CANbus, I²C, IEBus, SIO, UART/USART
Peripherals	DMA, PWM, WDT
Number of I/O	121
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 34x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LFQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m30845fjgp-u5

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1. Overview

The M32C/84 group (M32C/84, M32C/84T) microcomputer is a single-chip control unit that utilizes high-performance silicon gate CMOS technology with the M32C/80 series CPU core. The M32C/84 group (M32C/84, M32C/84T) is available in 144-pin and 100-pin plastic molded LQFP/QFP packages.

With a 16-Mbyte address space, this microcomputer combines advanced instruction manipulation capabilities to process complex instructions by less bytes and execute instructions at higher speed.

It includes a multiplier and DMAC adequate for office automation, communication devices and industrial equipments, and other high-speed processing applications.

1.1 Applications

Automobiles, audio, cameras, office equipment, communications equipment, portable equipment, etc.

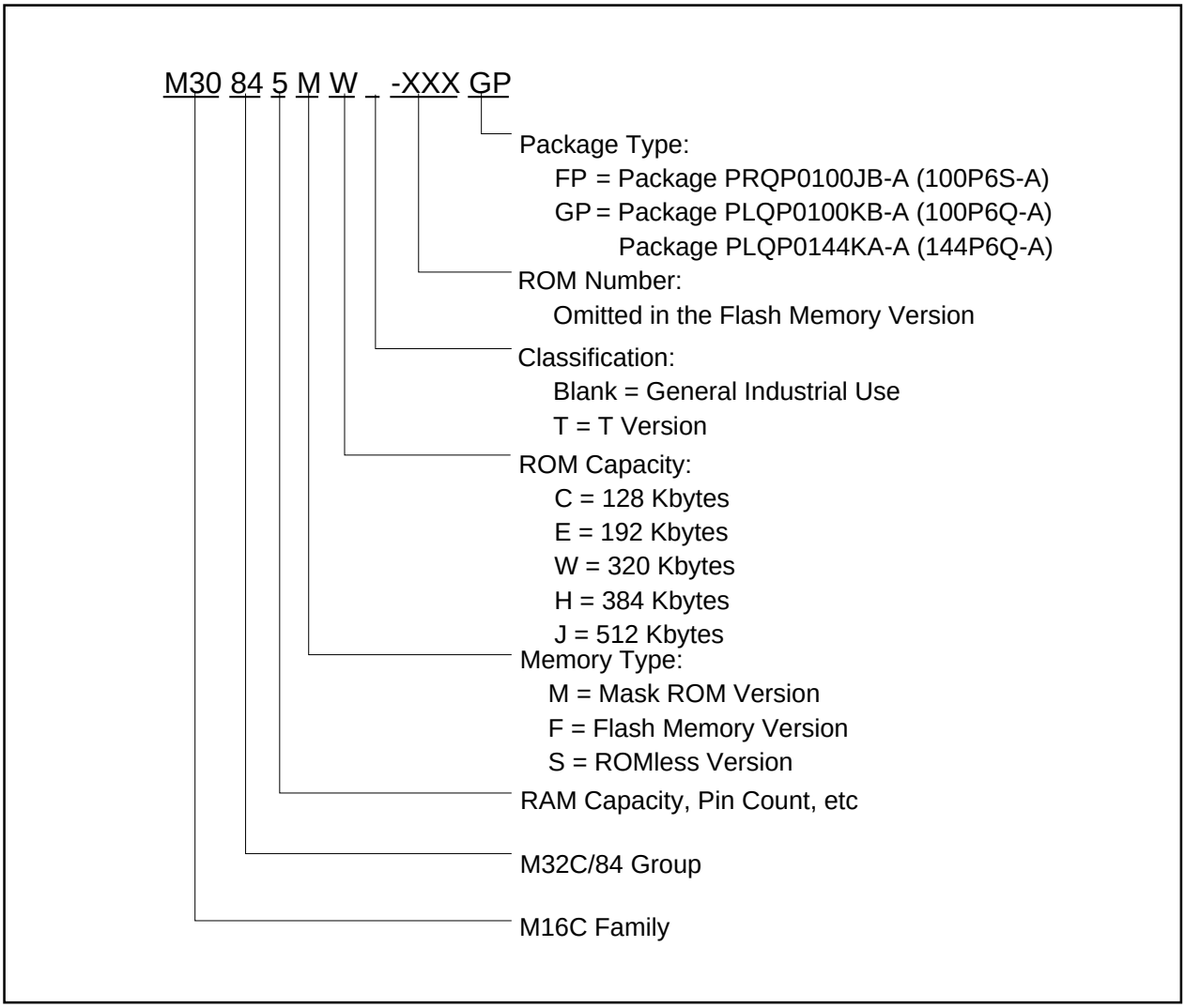


Figure 1.2 Product Numbering System

Table 1.6 Pin Description (144-Pin Package only) (Continued)

Classsfication	Symbol	I/O Type	Supply Voltage	Function
A/D Converter	$AN15_0$ to $AN15_7$	I	V_{CC1}	Analog input pins for the A/D converter
I/O Ports	$P11_0$ to $P11_4$ $P12_0$ to $P12_7$ $P13_0$ to $P13_7$	I/O	V_{CC2}	I/O ports having equivalent functions to P0
	$P14_0$ to $P14_6$ $P15_0$ to $P15_7$	I/O	V_{CC1}	I/O ports having equivalent functions to P0

I : Input O : Output I/O : Input and output

2.1.8.5 Register Bank Select Flag (B)

The register bank 0 is selected when the B flag is set to "0". The register bank 1 is selected when this flag is set to "1".

2.1.8.6 Overflow Flag (O)

The O flag is set to "1" when the result of an arithmetic operation overflows; otherwise "0".

2.1.8.7 Interrupt Enable Flag (I)

The I flag enables a maskable interrupt.
Interrupt is disabled when the I flag is set to "0" and enabled when the I flag is set to "1". The I flag is set to "0" when an interrupt is acknowledged.

2.1.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to "0". USP is selected when this flag is set to "1".
The U flag is set to "0" when a hardware interrupt is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

2.1.8.9 Processor Interrupt Priority Level (IPL)

IPL, 3 bits wide, assigns processor interrupt priority levels from level 0 to level 7.
If a requested interrupt has greater priority than IPL, the interrupt is enabled.

2.1.8.10 Reserved Space

When writing to a reserved space, set to "0". When reading, its content is indeterminate.

2.2 High-Speed Interrupt Registers

Registers associated with the high-speed interrupt are as follows:

- Flag save register (SVF)
- PC save register (SVP)
- Vector register (VCT)

2.3 DMAC-Associated Registers

Registers associated with DMAC are as follows:

- DMA mode register (DMD0, DMD1)
- DMA transfer count register (DCT0, DCT1)
- DMA transfer count reload register (DRC0, DRC1)
- DMA memory address register (DMA0, DMA1)
- DMA SFR address register (DSA0, DSA1)
- DMA memory address reload register (DRA0, DRA1)

Address	Register	Symbol	Value after RESET
00F0$_{16}$	Data Compare Register 00	G0CMP0	XX$_{16}$
00F1$_{16}$	Data Compare Register 01	G0CMP1	XX$_{16}$
00F2$_{16}$	Data Compare Register 02	G0CMP2	XX$_{16}$
00F3$_{16}$	Data Compare Register 03	G0CMP3	XX$_{16}$
00F4$_{16}$	Data Mask Register 00	G0MSK0	XX$_{16}$
00F5$_{16}$	Data Mask Register 01	G0MSK1	XX$_{16}$
00F6$_{16}$	Communication Clock Select Register	CCS	XXXX 0000$_2$
00F7$_{16}$			
00F8$_{16}$ 00F9$_{16}$	Receive CRC Code Register 0	G0RCRC	XX$_{16}$ XX$_{16}$
00FA$_{16}$ 00FB$_{16}$	Transmit CRC Code Register 0	G0TCRC	00$_{16}$ 00$_{16}$
00FC$_{16}$	SI/O Extended Mode Register 0	G0EMR	00$_{16}$
00FD$_{16}$	SI/O Extended Receive Control Register 0	G0ERC	00$_{16}$
00FE$_{16}$	SI/O Special Communication Interrupt Detect Register 0	G0IRF	00$_{16}$
00FF$_{16}$	SI/O Extended Transmit Control Register 0	G0ETC	0000 0XXX$_2$
0100$_{16}$ 0101$_{16}$	Time Measurement/Waveform Generating Register 10	G1TM0/G1PO0	XX$_{16}$ XX$_{16}$
0102$_{16}$ 0103$_{16}$	Time Measurement/Waveform Generating Register 11	G1TM1/G1PO1	XX$_{16}$ XX$_{16}$
0104$_{16}$ 0105$_{16}$	Time Measurement/Waveform Generating Register 12	G1TM2/G1PO2	XX$_{16}$ XX$_{16}$
0106$_{16}$ 0107$_{16}$	Time Measurement/Waveform Generating Register 13	G1TM3/G1PO3	XX$_{16}$ XX$_{16}$
0108$_{16}$ 0109$_{16}$	Time Measurement/Waveform Generating Register 14	G1TM4/G1PO4	XX$_{16}$ XX$_{16}$
010A$_{16}$ 010B$_{16}$	Time Measurement/Waveform Generating Register 15	G1TM5/G1PO5	XX$_{16}$ XX$_{16}$
010C$_{16}$ 010D$_{16}$	Time Measurement/Waveform Generating Register 16	G1TM6/G1PO6	XX$_{16}$ XX$_{16}$
010E$_{16}$ 010F$_{16}$	Time Measurement/Waveform Generating Register 17	G1TM7/G1PO7	XX$_{16}$ XX$_{16}$
0110$_{16}$	Waveform Generating Control Register 10	G1POCR0	0000 X000$_2$
0111$_{16}$	Waveform Generating Control Register 11	G1POCR1	0X00 X000$_2$
0112$_{16}$	Waveform Generating Control Register 12	G1POCR2	0X00 X000$_2$
0113$_{16}$	Waveform Generating Control Register 13	G1POCR3	0X00 X000$_2$
0114$_{16}$	Waveform Generating Control Register 14	G1POCR4	0X00 X000$_2$
0115$_{16}$	Waveform Generating Control Register 15	G1POCR5	0X00 X000$_2$
0116$_{16}$	Waveform Generating Control Register 16	G1POCR6	0X00 X000$_2$
0117$_{16}$	Waveform Generating Control Register 17	G1POCR7	0X00 X000$_2$
0118$_{16}$	Time Measurement Control Register 10	G1TMCR0	00$_{16}$
0119$_{16}$	Time Measurement Control Register 11	G1TMCR1	00$_{16}$
011A$_{16}$	Time Measurement Control Register 12	G1TMCR2	00$_{16}$
011B$_{16}$	Time Measurement Control Register 13	G1TMCR3	00$_{16}$
011C$_{16}$	Time Measurement Control Register 14	G1TMCR4	00$_{16}$
011D$_{16}$	Time Measurement Control Register 15	G1TMCR5	00$_{16}$
011E$_{16}$	Time Measurement Control Register 16	G1TMCR6	00$_{16}$
011F$_{16}$	Time Measurement Control Register 17	G1TMCR7	00$_{16}$

X: Indeterminate

Blank spaces are reserved. No access is allowed.

Address	Register	Symbol	Value after RESET
012016	Base Timer Register 1	G1BT	XX16
012116			XX16
012216	Base Timer Control Register 10	G1BCR0	0016
012316	Base Timer Control Register 11	G1BCR1	X000 000X2
012416	Time Measurement Prescaler Register 16	G1TPR6	0016
012516	Time Measurement Prescaler Register 17	G1TPR7	0016
012616	Function Enable Register 1	G1FE	0016
012716	Function Select Register 1	G1FS	0016
012816	SI/O Receive Buffer Register 1	G1RB	XXXX XXXX2
012916			X000 XXXX2
012A16	Transmit Buffer/Receive Data Register 1	G1TB/G1DR	XX16
012B16			
012C16	Receive Input Register 1	G1RI	XX16
012D16	SI/O Communication Mode Register 1	G1MR	0016
012E16	Transmit Output Register 1	G1TO	XX16
012F16	SI/O Communication Control Register 1	G1CR	0000 X0112
013016	Data Compare Register 10	G1CMP0	XX16
013116	Data Compare Register 11	G1CMP1	XX16
013216	Data Compare Register 12	G1CMP2	XX16
013316	Data Compare Register 13	G1CMP3	XX16
013416	Data Mask Register 10	G1MSK0	XX16
013516	Data Mask Register 11	G1MSK1	XX16
013616			
013716			
013816	Receive CRC Code Register 1	G1RCRC	XX16
013916			XX16
013A16	Transmit CRC Code Register 1	G1TCRC	0016
013B16			0016
013C16	SI/O Extended Mode Register 1	G1EMR	0016
013D16	SI/O Extended Receive Control Register 1	G1ERC	0016
013E16	SI/O Special Communication Interrupt Detect Register 1	G1IRF	0016
013F16	SI/O Extended Transmit Control Register 1	G1ETC	0000 0XXX2
014016			
014116			
014216			
014316			
014416			
014516			
014616			
014716			
014816			
014916			
014A16			
014B16			
014C16			
014D16			
014E16			
014F16			

X: Indeterminate

Blank spaces are reserved. No access is allowed.

Address	Register	Symbol	Value after RESET
021016 021116	CAN0 Slot Interrupt Mask Register	C0SIMKR	0016(2) 0016(2)
021216			
021316			
021416	CAN0 Error Interrupt Mask Register	C0EIMKR	XXXX X0002(2)
021516	CAN0 Error Interrupt Status Register	C0EISTR	XXXX X0002(2)
021616	CAN0 Error Cause Register	C0EFR	0016(2)
021716	CAN0 Baud Rate Prescaler	C0BRP	0000 00012(2)
021816			
021916	CAN0 Mode Register	C0MDR	XXXX XX002(2)
021A16			
021B16			
021C16			
021D16			
021E16			
021F16			
022016 022116	CAN0 Single-Shot Control Register	C0SSCTLR	0016(2) 0016(2)
022216			
022316			
022416 022516	CAN0 Single-Shot Status Register	C0SSSTR	0016(2) 0016(2)
022616			
022716			
022816	CAN0 Global Mask Register Standard ID0	C0GMR0	XXX0 00002(2)
022916	CAN0 Global Mask Register Standard ID1	C0GMR1	XX00 00002(2)
022A16	CAN0 Global Mask Register Extended ID0	C0GMR2	XXXX 00002(2)
022B16	CAN0 Global Mask Register Extended ID1	C0GMR3	0016(2)
022C16	CAN0 Global Mask Register Extended ID2	C0GMR4	XX00 00002(2)
022D16			
022E16			
022F16			
023016	CAN0 Message Slot 0 Control Register / CAN0 Local Mask Register A Standard ID0	C0MCTL0/ C0LMAR0	0000 00002(2) XXX0 00002(2)
023116	CAN0 Message Slot 1 Control Register / CAN0 Local Mask Register A Standard ID1	C0MCTL1/ C0LMAR1	0000 00002(2) XX00 00002(2)
023216	CAN0 Message Slot 2 Control Register / CAN0 Local Mask Register A Extended ID0	C0MCTL2/ C0LMAR2	0000 00002(2) XXXX 00002(2)
023316	CAN0 Message Slot 3 Control Register / CAN0 local Mask Register A Extended ID1	C0MCTL3/ C0LMAR3	0016(2) 0016(2)
023416	CAN0 Message Slot 4 Control Register / CAN0 Local Mask Register A Extended ID2	C0MCTL4/ C0LMAR4	0000 00002(2) XX00 00002(2)
023516	CAN0 Message Slot 5 Control Register	C0MCTL5	0016(2)
023616	CAN0 Message Slot 6 Control Register	C0MCTL6	0016(2)
023716	CAN0 Message Slot 7 Control Register	C0MCTL7	0016(2)
023816	CAN0 Message Slot 8 Control Register / CAN0 Local Mask Register B Standard ID0	C0MCTL8/ C0LMBR0	0000 00002(2) XXX0 00002(2)

(Note 1)

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. The BANKSEL bit in the C0CTLR1 register switches functions for addresses 022016 to 023F16.
2. Values are obtained by setting the SLEEP bit in the C0SLPR register to "1" (sleep mode exited) after reset and supplying the clock to the CAN module.

5. Electrical Characteristics

5.1 Electrical Characteristics (M32C/84)

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter		Condition	Value	Unit
V_{CC1}, V_{CC2}	Supply Voltage		V_{CC1}=AV$_{CC}$	-0.3 to 6.0	V
V_{CC2}	Supply Voltage		-	-0.3 to V_{CC1}	V
AV$_{CC}$	Analog Supply Voltage		V_{CC1}=AV$_{CC}$	-0.3 to 6.0	V
V_I	Input Voltage	$\overline{RESET}$, CNV$_{SS}$, BYTE, P6$_0$-P6$_7$, P7$_2$-P7$_7$, P8$_0$-P8$_7$, P9$_0$-P9$_7$, P10$_0$-P10$_7$, P14$_0$-P14$_6$, P15$_0$-P15$_7$(1), V_{REF}, X_{IN}		-0.3 to V_{CC1}+0.3	V
		P0$_0$-P0$_7$, P1$_0$-P1$_7$, P2$_0$-P2$_7$, P3$_0$-P3$_7$, P4$_0$-P4$_7$, P5$_0$-P5$_7$, P11$_0$-P11$_4$, P12$_0$-P12$_7$, P13$_0$-P13$_7$(1)		-0.3 to V_{CC2}+0.3	
		P7$_0$, P7$_1$		-0.3 to 6.0	
V_O	Output Voltage	P6$_0$-P6$_7$, P7$_2$-P7$_7$, P8$_0$-P8$_4$, P8$_6$, P8$_7$, P9$_0$-P9$_7$, P10$_0$-P10$_7$, P14$_0$-P14$_6$, P15$_0$-P15$_7$(1), X_{OUT}		-0.3 to V_{CC1}+0.3	V
		P0$_0$-P0$_7$, P1$_0$-P1$_7$, P2$_0$-P2$_7$, P3$_0$-P3$_7$, P4$_0$-P4$_7$, P5$_0$-P5$_7$, P11$_0$-P11$_4$, P12$_0$-P12$_7$, P13$_0$-P13$_7$(1)		-0.3 to V_{CC2}+0.3	
		P7$_0$, P7$_1$		-0.3 to 6.0	
Pd	Power Dissipation		Topr=25° C	500	mW
Topr	Operating Ambient Temperature	during CPU operation		-20 to 85/ -40 to 85(2)	° C
		during flash memory program and erase operation		0 to 60	
Tstg	Storage Temperature			-65 to 150	° C

NOTES:
1. P11 to P15 are provided in the 144-pin package only.
2. Contact Renesas Technology Sales Co., Ltd, if temperature range of -40 to 85° C is required.

Table 5.2 Recommended Operating Conditions (Continued)
(V_{CC1}=V_{CC2}=3.0V to 5.5V at Topr=–20 to 85°C unless otherwise specified)

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
$f(BCLK)$	CPU Clock Frequency	V_{CC1}=4.2 to 5.5V	0		32	MHz
		V_{CC1}=3.0 to 5.5V	0		24	MHz
$f(X_{IN})$	Main Clock Input Frequency	V_{CC1}=4.2 to 5.5V	0		32	MHz
		V_{CC1}=3.0 to 5.5V	0		24	MHz
$f(X_{CIN})$	Sub Clock Frequency			32.768	50	kHz
$f(Ring)$	On-chip Oscillator Frequency (V_{CC1}=V_{CC2}=5.0V, Topr=25° C)		0.5	1	2	MHz
$f(PLL)$	PLL Clock Frequency	V_{CC1}=4.2 to 5.5V	10		32	MHz
		V_{CC1}=3.0 to 5.5V	10		24	MHz
$t_{SU(PLL)}$	Wait Time to Stabilize PLL Frequency Synthesizer	V_{CC1}=5.0V			5	ms
		V_{CC1}=3.3V			10	ms

$V_{CC1}=V_{CC2}=5V$

Table 5.3 Electrical Characteristics

($V_{CC1}=V_{CC2}=4.2$ to 5.5V, $V_{SS}=0V$ at Topr= –20 to 85°C, f(BCLK)=32MHz unless otherwise specified)

Symbol	Parameter		Condition	Standard			Unit
				Min.	Typ.	Max.	
V_{OH}	Output High ("H") Voltage	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$	I_{OH}=-5mA	V_{CC2}-2.0		V_{CC2}	V
		$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OH}=-5mA	V_{CC1}-2.0		V_{CC1}	
		$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$	I_{OH}=-200µA	V_{CC2}-0.3		V_{CC2}	V
		$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$,$P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OH}=-200µA	V_{CC1}-0.3		V_{CC1}	
		X_{OUT}	I_{OH}=-1mA	3.0		V_{CC1}	V
		X_{COUT} High Power	No load applied		2.5		V
		X_{COUT} Low Power	No load applied		1.6		
V_{OL}	Output Low ("L") Voltage	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OL}=5mA			2.0	V
		$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OL}=200µA			0.45	V
		X_{OUT}	I_{OL}=1mA			2.0	V
		X_{COUT} High Power	No load applied		0		V
		X_{COUT} Low Power	No load applied		0		
V_{T+}-V_{T-}	Hysteresis	$\overline{HOLD}$, $\overline{RDY}$, $TA0_{IN}$-$TA4_{IN}$, $TB0_{IN}$-$TB5_{IN}$, $\overline{INT0}$-$\overline{INT5}$, $\overline{ADTRG}$, $\overline{CTS0}$-$\overline{CTS4}$, CLK0-CLK4, $TA0_{OUT}$-$TA4_{OUT}$, $\overline{NMI}$, $\overline{KI0}$-$\overline{KI3}$, RxD0-RxD4, SCL0-SCL4, SDA0-SDA4		0.2		1.0	V
		$\overline{RESET}$		0.2		1.8	V
I_{IH}	Input High ("H") Current	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{IN}, $\overline{RESET}$, CNV_{SS}, BYTE	V_I=5V			5.0	µA
I_{IL}	Input Low ("L") Current	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{IN}, $\overline{RESET}$, CNV_{SS}, BYTE	V_I=0V			-5.0	µA
R_{PULLUP}	Pull-up Resistance	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	V_I=0V Flash Memory	30	50	167	kΩ
			Masked ROM	20	40	167	
Rf_{XIN}	Feedback Resistance	X_{IN}			1.5		MΩ
Rf_{XCIN}	Feedback Resistance	X_{CIN}			10		MΩ
V_{RAM}	RAM Standby Voltage	In stop mode		2.0			V

NOTES:

1. P11 to P15 are provided in the 144-pin package only.

$V_{CC1}=V_{CC2}=5V$

Table 5.4 A/D Conversion Characteristics ($V_{CC1}=V_{CC2}=AV_{CC}=V_{REF}$=4.2 to 5.5V, V_{SS}= AV_{SS} = 0V at Topr=–20 to 85°C, f(BCLK) = 32MHz unless otherwise specified)

Symbol	Parameter	Measurement Condition		Standard			Unit
				Min.	Typ.	Max.	
-	Resolution	$V_{REF}=V_{CC1}$				10	Bits
INL	Integral Nonlinearity Error	$V_{REF}=V_{CC1}=V_{CC2}$=5V	AN_0 to AN_7, $AN0_0$ to $AN0_7$, $AN2_0$ to $AN2_7$, $AN15_0$ to $AN15_7$, ANEX0, ANEX1			±3	LSB
							LSB
			External op-amp connection mode			±7	LSB
							LSB
DNL	Differential Nonlinearity Error					±1	LSB
-	Offset Error					±3	LSB
-	Gain Error					±3	LSB
R_{LADDER}	Resistor Ladder	$V_{REF}=V_{CC1}$		8		40	kΩ
t_{CONV}	10-bit Conversion Time(1, 2)			2.06			µs
t_{CONV}	8-bit Conversion Time(1, 2)			1.75			µs
t_{SAMP}	Sampling Time(1)			0.188			µs
V_{REF}	Reference Voltage			2		V_{CC1}	V
V_{IA}	Analog Input Voltage			0		V_{REF}	V

NOTES:
1. Divide f(X_{IN}), if exceeding 16 MHz, to keep ϕAD frequency at 16 MHz or less.
2. With using the sample and hold function.

Table 5.5 D/A Conversion Characteristics ($V_{CC1}=V_{CC2}=V_{REF}$=4.2 to 5.5V, $V_{SS}=AV_{SS}$=0V at Topr=–20 to 85°C, f(BCLK) = 32MHz unless otherwise specified)

Symbol	Parameter	Measurement Condition	Standard			Unit
			Min.	Typ.	Max.	
-	Resolution				8	Bits
-	Absolute Accuracy				1.0	%
t_{SU}	Setup Time				3	µs
R_O	Output Resistance		4	10	20	kΩ
I_{VREF}	Reference Power Supply Input Current	(Note 1)			1.5	mA

NOTES:
1. Measurement when using one D/A converter. The DAi register (i=0, 1) of the D/A converter, not being used, is set to "00_{16}". The resistor ladder in the A/D converter is excluded.
I_{VREF} flows even if the VCUT bit in the AD0CON1 register is set to "0" (no V_{REF} connection).

$V_{CC1}=V_{CC2}=5V$

Switching Characteristics

(V_{CC} = 4.2 to 5.5V, V_{SS} = 0V at Topr = –20 to 85°C unless otherwise specified)

Table 5.23 Memory Expansion Mode and Microprocessor Mode

(when accessing an external memory space with the multiplexed bus)

Symbol	Parameter	Measurement Condition	Standard		Unit
			Min.	Max.	
td(BCLK-AD)	Address Output Delay Time	See Figure 5.2		18	ns
th(BCLK-AD)	Address Output Hold Time (BCLK standard)		-3		ns
th(RD-AD)	Address Output Hold Time (RD standard)(5)		(Note 1)		ns
th(WR-AD)	Address Output Hold Time (WR standard)(5)		(Note 1)		ns
td(BCLK-CS)	Chip-Select Signal Output Delay Time			18	ns
th(BCLK-CS)	Chip-Select Signal Output Hold Time (BCLK standard)		-3		ns
th(RD-CS)	Chip-Select Signal Output Hold Time (RD standard)(5)		(Note 1)		ns
th(WR-CS)	Chip-Select Signal Output Hold Time (WR standard)(5)		(Note 1)		ns
td(BCLK-RD)	RD Signal Output Delay Time			18	ns
th(BCLK-RD)	RD Signal Output Hold Time		-5		ns
td(BCLK-WR)	WR Signal Output Delay Time			18	ns
th(BCLK-WR)	WR Signal Output Hold Time		-5		ns
td(DB-WR)	Data Output Delay Time (WR standard)		(Note 2)		ns
th(WR-DB)	Data Output Hold Time (WR standard)(5)		(Note 1)		ns
td(BCLK-ALE)	ALE Signal Output Delay Time (BCLK standard)			18	ns
th(BCLK-ALE)	ALE Signal Output Hold Time (BCLK standard)		-2		ns
td(AD-ALE)	ALE Signal Output Delay Time (address standard)		(Note 3)		ns
th(ALE-AD)	ALE Signal Output Hold Time (address standard)		(Note 4)		ns
tdz(RD-AD)	Address Output Float Start Time			8	ns

NOTES:

1. Values can be obtained from the following equations, according to BCLK frequency.

$$th(RD-AD) = \frac{10^9}{f(BCLK) \times 2} - 10 \quad [ns]$$

$$th(WR-AD) = \frac{10^9}{f(BCLK) \times 2} - 10 \quad [ns]$$

$$th(RD-CS) = \frac{10^9}{f(BCLK) \times 2} - 10 \quad [ns]$$

$$th(WR-CS) = \frac{10^9}{f(BCLK) \times 2} - 10 \quad [ns]$$

$$th(WR-DB) = \frac{10^9}{f(BCLK) \times 2} - 10 \quad [ns]$$

2. Values can be obtained from the following equations, according to BCLK frequency and external bus cycle.

$$td(DB-WR) = \frac{10^9 \times m}{f(BCLK) \times 2} - 25 \quad [ns]$$ (if external bus cycle is aϕ + bϕ, m= (bx2)-1)

3. Values can be obtained from the following equations, according to BCLK frequency and external bus cycle.

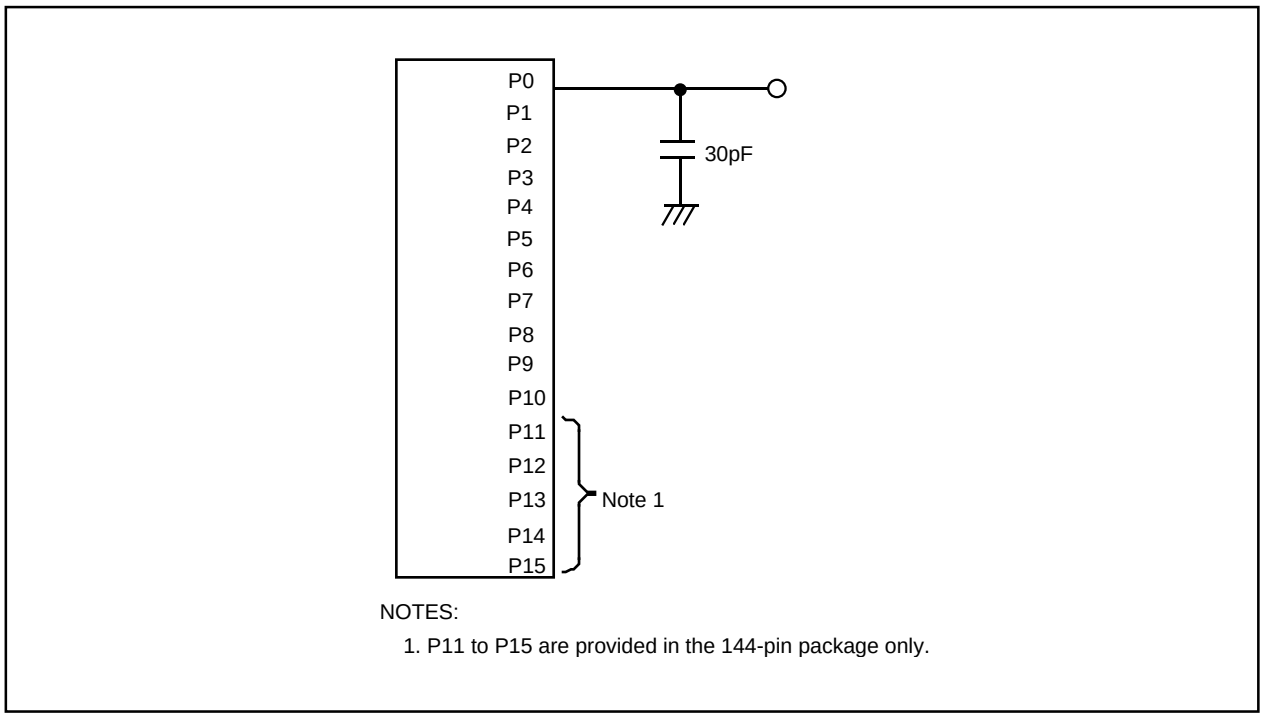
$$td(AD-ALE) = \frac{10^9 \times n}{f(BCLK) \times 2} - 20 \quad [ns]$$ (if external bus cycle is aϕ + bϕ, n= a)

4. Values can be obtained from the following equations, according to BCLK frequency and external bus cycle.

$$th(ALE-AD) = \frac{10^9 \times n}{f(BCLK) \times 2} - 10 \quad [ns]$$ (if external bus cycle is aϕ + bϕ, n= a)

5. *tc* ns is added when recovery cycle is inserted.

$V_{CC1}=V_{CC2}=5V$



NOTES:
1. P11 to P15 are provided in the 144-pin package only.

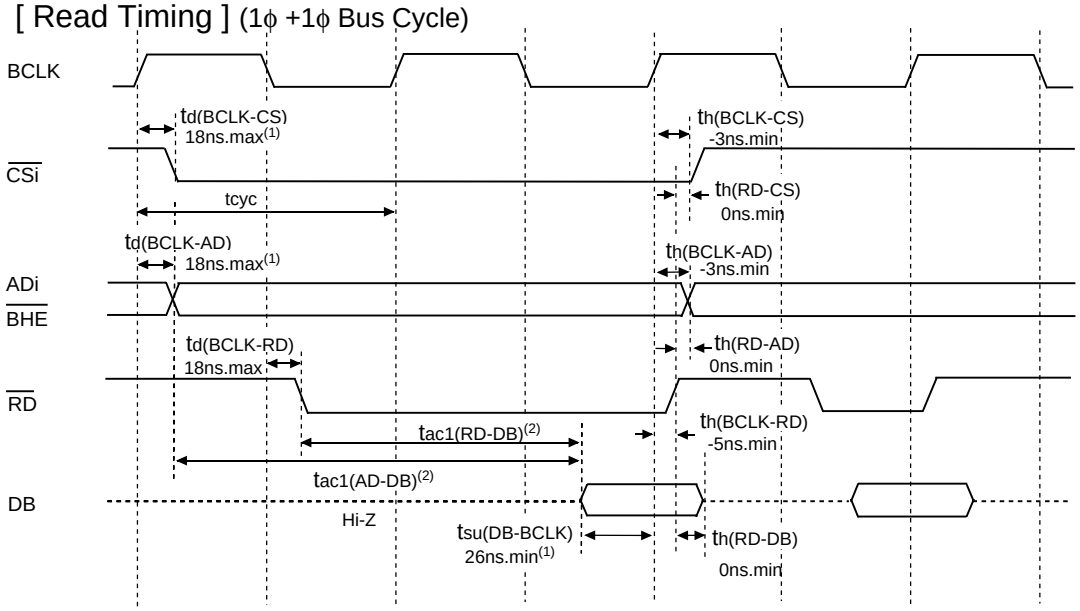
Figure 5.2 P0 to P15 Measurement Circuit

Vcc1=Vcc2=5V

Memory Expansion Mode and Microprocessor Mode

(when accessing an external memory space)

[Read Timing] (1ϕ +1ϕ Bus Cycle)



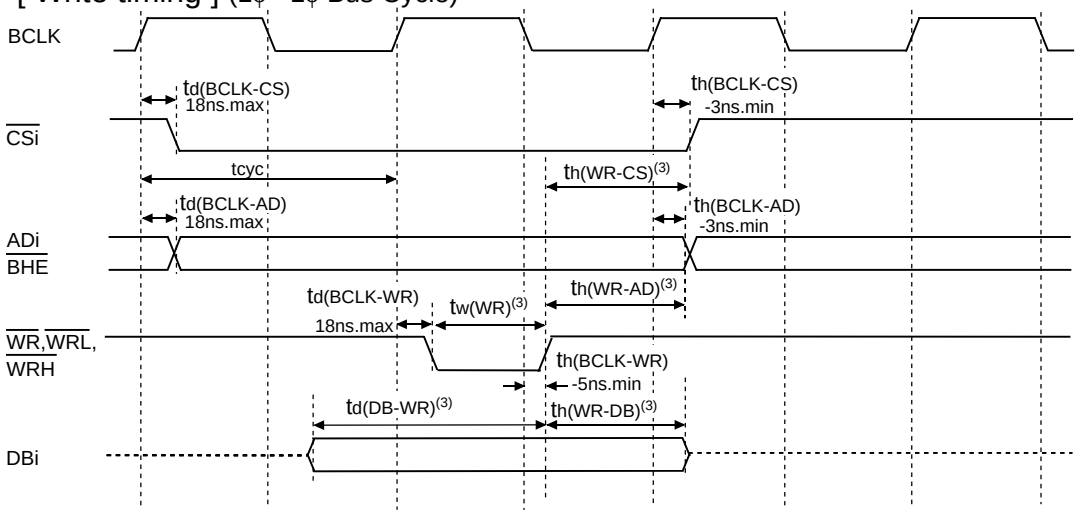
NOTES:

1. Values guaranteed only when the microcomputer is used independently.
A maximum of 35ns is guaranteed for $t_{d(BCLK-AD)}+t_{su(DB-BCLK)}$.
2. Varies with operation frequency:

$t_{ac1(RD-DB)}$=(tcyc/2 x m-35)ns.max (if external bus cycle is aϕ + bϕ, m=(b x 2)+1)

$t_{ac1(AD-DB)}$=(tcyc x n-35)ns.max (if external bus cycle is aϕ + bϕ, n=a+b)

[Write timing] (1ϕ +1ϕ Bus Cycle)



NOTES:

3. Varies with operation frequency:
$t_{d(DB-WR)}$=(tcyc x m-20)ns.min
(if external bus cycle is aϕ+bϕ, m=b)
$t_{h(WR-DB)}$=(tcyc/2-10)ns.min
$t_{h(WR-AD)}$=(tcyc/2-10)ns.min
$t_{h(WR-CS)}$=(tcyc/2-10)ns.min
$t_{w(WR)}$=(tcyc/2 x n-15)ns.min
(if external bus cycle is aϕ+bϕ , n=(bx2)-1)

Measurement Conditions:

- V_{CC1}=V_{CC2}=4.2 to 5.5V
- Input high and low voltage: V_{IH}=2.5V, V_{IL}=0.8V
- Output high and low voltage: V_{OH}=2.0V, V_{OL}=0.8V

$$tcyc = \frac{10^9}{f(BCLK)}$$

Figure 5.3 Vcc1=Vcc2=5V Timing Diagram (1)

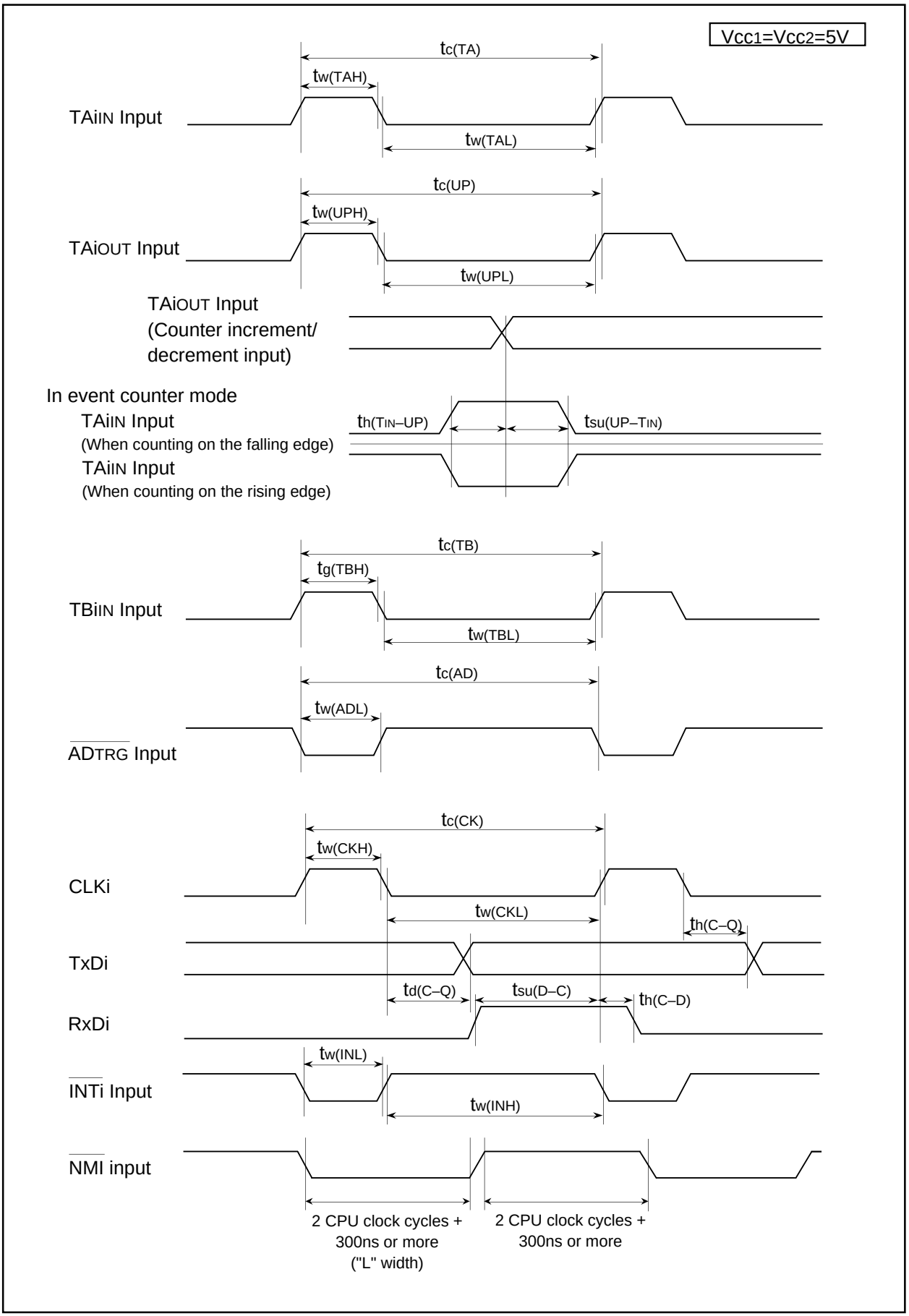


Figure 5.5 Vcc1=Vcc2=5V Timing Diagram (3)

$V_{CC1}=V_{CC2}=3.3V$

Table 5.24 Electrical Characteristics ($V_{CC1}=V_{CC2}=3.0$ to $3.6V$, $V_{SS}=0V$ at Topr = –20 to 85°C, f(BCLK)=24MHz unless otherwise specified)

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
V_{OH}	Output High ("H") Voltage	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$	I_{OH}=-1mA		V_{CC2}-0.6		V_{CC2}	V
		$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)			V_{CC1}-0.6		V_{CC1}	V
		X_{OUT}	I_{OH}=-0.1mA		2.7		V_{CC1}	V
		X_{COUT} High Power	No load applied			2.5		V
		X_{COUT} Low Power	No load applied			1.6		V
V_{OL}	Output Low ("L") Voltage	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OL}=1mA				0.5	V
		X_{OUT}	I_{OL}=0.1mA				0.5	V
		X_{COUT} High Power	No load applied			0		V
		X_{COUT} Low Power	No load applied			0		V
V_{T+}-V_{T-}	Hysteresis	$\overline{HOLD}$, $\overline{RDY}$, $TA0_{IN}$-$TA4_{IN}$, $TB0_{IN}$-$TB5_{IN}$, $\overline{INT0}$-$\overline{INT5}$, $\overline{ADTRG}$, $\overline{CTS0}$-$\overline{CTS4}$, CLK0-CLK4, $TA0_{OUT}$-$TA4_{OUT}$, $\overline{NMI}$, $\overline{KI0}$-$\overline{KI3}$, RxD0-RxD4, SCL0-SCL4, SDA0-SDA4			0.2		1.0	V
		$\overline{RESET}$			0.2		1.8	V
I_{IH}	Input High ("H") Current	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{IN}, $\overline{RESET}$, CNV_{SS}, BYTE	V_I=3V				4.0	µA
I_{IL}	Input Low ("L") Current	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{IN}, $\overline{RESET}$, CNV_{SS}, BYTE	V_I=0V				-4.0	µA
R_{PULLUP}	Pull-up Resistance	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	V_I=0V	Flash Memory	66	120	500	kΩ
				Masked ROM	40	70	500	kΩ
R_{fXIN}	Feedback Resistance	X_{IN}				3.0		MΩ
R_{fXCIN}	Feedback Resistance	X_{CIN}				20.0		MΩ
V_{RAM}	RAM Standby Voltage	in stop mode			2.0			V
I_{CC}	Power Supply Current	Measurement condition: In single-chip mode, output pins are left open and other pins are connected to V_{SS}.	f(BCLK)=24 MHz, Square wave, No division			22	35	mA
			f(BCLK)=32 kHz, In wait mode, Topr=25° C			10		µA
			While clock stops, Topr=25° C			0.8	5	µA
			While clock stops, Topr=85° C				50	µA

NOTES:

1. P11 to P15 are provided in the 144-pin package only.

$V_{CC1}=V_{CC2}=3.3V$

Table 5.25 A/D Conversion Characteristics ($V_{CC1}=V_{CC2}=AV_{CC}=V_{REF}$= 3.0 to 3.6V, $V_{SS}=AV_{SS}$=0V at Topr = –20 to 85°C, f(BCLK) = 24MHz unless otherwise specified)

Symbol	Parameter		Measurement Condition	Standard			Unit
				Min.	Typ.	Max.	
-	Resolution		$V_{REF}=V_{CC1}$			10	Bits
INL	Integral Nonlinearity Error	No S&H (8-bit)	$V_{CC1}=V_{CC2}=V_{REF}$=3.3V			±2	LSB
DNL	Differential Nonlinearity Error	No S&H (8-bit)				±1	LSB
-	Offset Error	No S&H (8-bit)				±2	LSB
-	Gain Error	No S&H (8-bit)				±2	LSB
R_{LADDER}	Resistor Ladder		$V_{REF}=V_{CC1}$	8		40	kΩ
t_{CONV}	8-bit Conversion Time(1, 2)			6.1			µs
V_{REF}	Reference Voltage			3		V_{CC1}	V
V_{IA}	Analog Input Voltage			0		V_{REF}	V

S&H: Sample and Hold

NOTES:
1. Divide f(X_{IN}), if exceeding 10 MHz, to keep ϕAD frequency at 10 MHz or less.
2. S&H not available.

Table 5.26 D/A Conversion Characteristics ($V_{CC1}=V_{CC2}=V_{REF}$=3.0 to 3.6V, $V_{SS}=AV_{SS}$=0V at Topr = –20 to 85°C, f(BCLK) = 24MHz unless otherwise specified)

Symbol	Parameter	Measurement Condition	Standard			Unit
			Min.	Typ.	Max.	
-	Resolution				8	Bits
-	Absolute Accuracy				1.0	%
t_{SU}	Setup Time				3	µs
R_O	Output Resistance		4	10	20	kΩ
I_{VREF}	Reference Power Supply Input Current	(Note 1)			1.0	mA

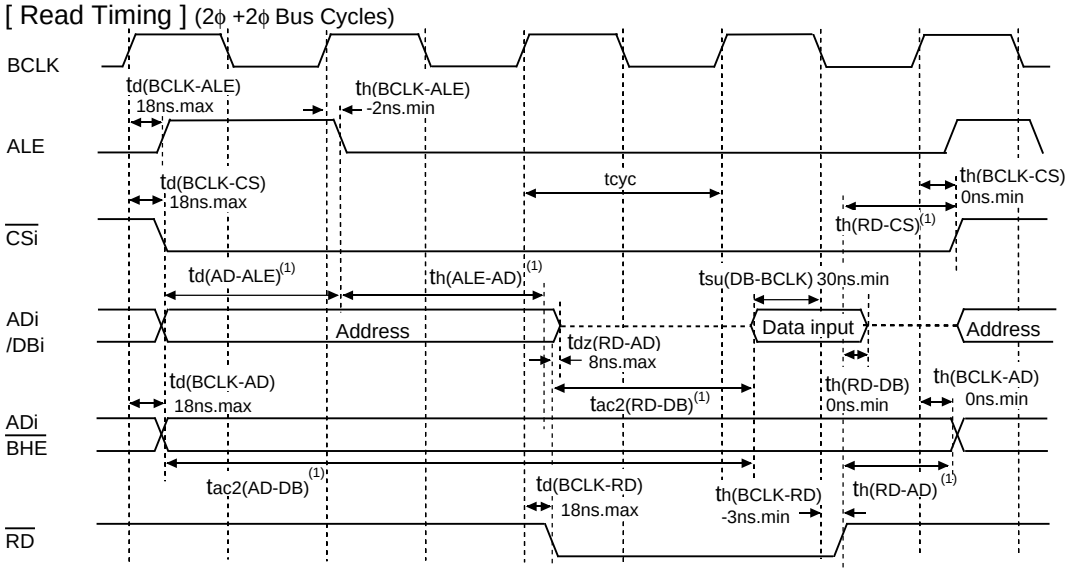
NOTES:
1. Measurement results when using one D/A converter. The DAi register (i=0, 1) of the D/A converter, not being used, is set to "00_{16}". The resistor ladder in the A/D converter is excluded.
I_{VREF} flows even if the VCUT bit in the AD0CON1 register is set to "0" (no V_{REF} connection).

Memory Expansion Mode and Microprocessor Mode

$V_{CC1}=V_{CC2}=3.3V$

(when accessing external memory space and using the multiplexed bus)

[Read Timing] (2φ +2φ Bus Cycles)



NOTES:

1. Varies with operation frequency:

$t_{d(AD-ALE)}$=(tcyc/2 x n-20)ns.min (if external bus cycle is aφ + bφ, n=a)

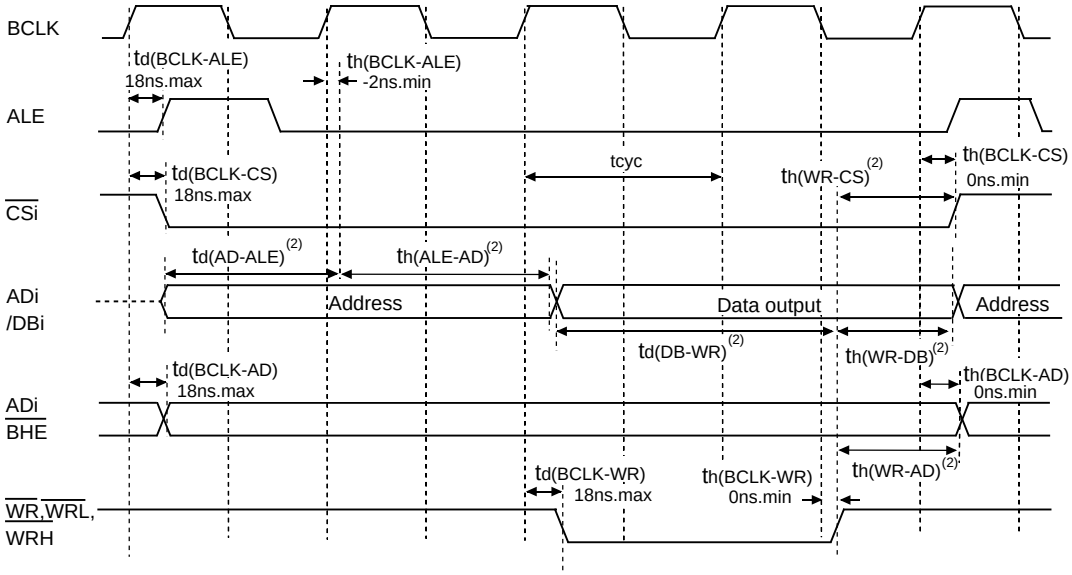
$t_{h(ALE-AD)}$=(tcyc/2 x n-10)ns.min (if external bus cycle is aφ + bφ, n=a)

$t_{h(RD-AD)}$=(tcyc/2-10)ns.min, $t_{h(RD-CS)}$=(tcyc/2-10)ns.min

$t_{ac2(RD-DB)}$=(tcyc/2 x m-35)ns.max (if external bus cycle is aφ + bφ, m=(b x 2)-1)

$t_{ac2(AD-DB)}$=(tcyc/2 x p-35)ns.max (if external bus cycle is aφ + bφ, p={(a+b-1) x 2}+1)

[Write Timing] (2φ +2φ Bus Cycles)



NOTES:

2. Varies with operation frequency:

$t_{d(AD-ALE)}$=(tcyc/2 x n - 20)ns.min

(if external bus cycle is aφ + bφ, n=a)

$t_{h(ALE-AD)}$=(tcyc/2 x n -10)ns.min

(if external bus cycle is aφ + bφ, n=a)

$t_{h(WR-AD)}$=(tcyc/2-10)ns.min,

$t_{h(WR-CS)}$=(tcyc/2-10)ns.min, $t_{h(WR-DB)}$=(tcyc/2-20)ns.min

$t_{d(DB-WR)}$=(tcyc/2 x m-25)ns.min

(if external bus cycle is aφ + bφ, m=(b x 2)-1)

Measurement Conditions:

- $V_{CC1}=V_{CC2}$=3.0 to 3.6V
- Input high and low voltage: V_{IH}=1.5V, V_{IL}=0.5V
- Output high and low voltage: V_{OH}=1.5V, V_{OL}=1.5V

$$tcyc=\frac{10^9}{f_{(BCLK)}}$$

Figure 5.8 $V_{CC1}=V_{CC2}$=3.3V Timing Diagram (2)

Table 5.43 Recommended Operating Conditions (Continued)

(V_{CC1}=V_{CC2}=4.2 to 5.5V, V_{SS}=0V at Topr = -40 to 85°C (T version) unless otherwise specified)

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
$f(BCLK)$	CPU Input Frequency	V_{CC1}=4.2 to 5.5V	0		32	MHz
$f(X_{IN})$	Main Clock Input Frequency	V_{CC1}=4.2 to 5.5V	0		32	MHz
$f(X_{CIN})$	Sub Clock Frequency			32.768	50	kHz
$f(Ring)$	On-chip Oscillator Frequency (V_{CC1}=V_{CC2}=5.0V, Topr=25° C)		0.5	1	2	MHz
$f(PLL)$	PLL Clock Frequency	V_{CC1}=4.2 to 5.5V	10		32	MHz
$t_{SU(PLL)}$	Wait Time to Stabilize PLL Frequency Synthesizer	V_{CC1}=5.0V			5	ms

REVISION HISTORY	M32C/84 Group (M32C/84, M32C/84T) Datasheet

Rev.	Date	Description	
		Page	Summary
1.00	Jun.01, 2004	-	**M32C/84T (High-reliability version)** added
		All Pages	Words standardized: On-chip oscillator, A/D converter and D/A converter
			Overview
		1	• **1.1 Applications** Automobiles added
		2, 3	• **Table 1.1** and **Table 1.2 M32C/84 Group (M32C/84, M32C/84T) Performance** M32C/84T added; note 3 added
		4	• **Figure 1.1 M32C/84 Group (M32C/84, M32C/84T) Block Diagram** Note 3 added
		5	• **1.4 Product Information** Description modified
			• **Figure 1.2 ROM/RAM Capacity** figure modified
		6	• **Table 1.3 M32C/84 Group** M32C/84T added
		6	• **Figure 1.3 Product Numbering System** M32C/84T added
		7	• **Figure 1.4 Pin Assignment for 144-Pin Package** Note 3 added
		12	• **Figure 1.6 Pin Assignment for 100-Pin Pacakage** Note 5 added
		8 to 10	• **Table 1.5 Pin Characteristics for 144-Pin Package** Note 1 added
		13, 14	• **Table 1.6 Pin Characteristics for 100-Pin Package** Note 1 added
		15 to 18	• **Table 1.7 Pin Description** Notes added
			Memory
		22	• **Figure 3.1 Memory Map** Tables of internal ROM/internal RAM modified; note 2 modified; notes 4 and 5 added
			SFR
		23	• Note 2 added
		24	• PWCR0 and PWCR1 registers deleted
			• "Values after RESET" of the masked ROM version added to the FMR0 register
			• Note 1 added
			Electrical Characteristics
		44	• **Table 5.2 Recommended Operating Conditions** $f_{(ripple)}$, $V_{p-p(ripple)}$, V_{CC}, SV_{CC} and note 1 deleted
		47	• **Table 5.3 Electrical Characteristics** R_{PULLUP} value for the masked ROM version added
		48	• **Table 5.4 A/D Conversion Characteristics** t_{SMP} value modified; note 1 added
		50	• **Table 5.7 Low Voltage Detect Circuit Electrical Characteristics** added
			• **Table 5.8 Power Supply Timing** added
			• **Figure 5.1 Power Supply Timing Diagram** added
		55	• **Table 5.23 Memory Expassion Mode and Microprocessor Mode** $t_{h(BCLK-ALE)}$ value modified
		61	• **Table 5.24 Electrical Characteristics** R_{PULLUP} value for the masked ROM version added
		62	• **Table 5.25 A/D Conversion Characteristics** t_{CONV} value modified